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- INFORMATION DISCLOSURE CITATION IN AN - APPLICATION						ATTY. DOCKET NO. 57454-964	Div	SERIAL NO. Divisional of Appl. No. 09/832,025		
						APPLICANT Hideto HIDAKA				
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^{*}EXAMINER: Initial if reference considéred, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

1 Applicant's unique citation designation number (optional). 2 Applicant is to place a check mark here if English language Translation is attached.